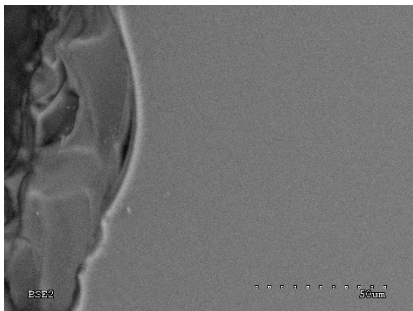
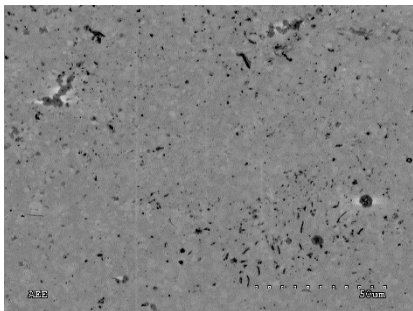
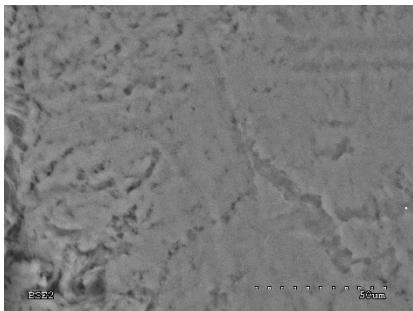
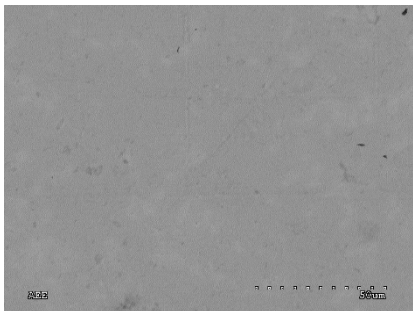
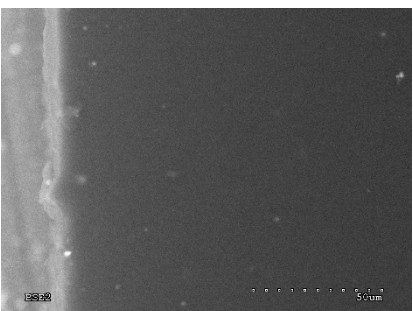
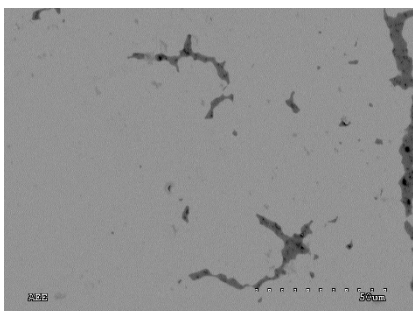


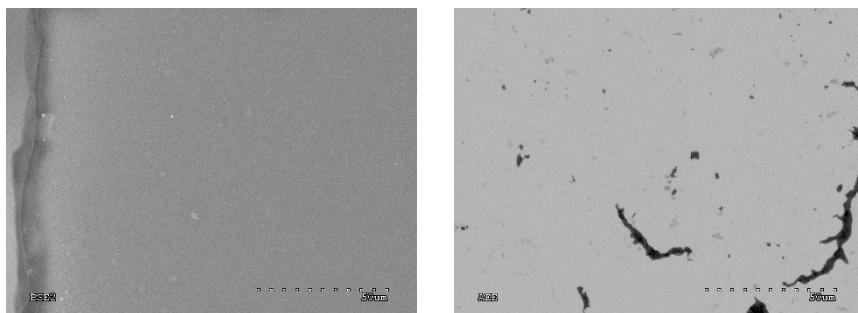
Supplementary Materials

# Influence of the Interactions at the Graphene–Substrate Boundary on Graphene Sensitivity to UV Irradiation

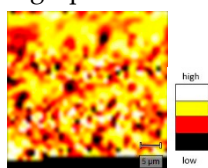
Dorota Nowak <sup>1,\*</sup>, Marian Clapa <sup>1,2</sup>, Piotr Kula <sup>1</sup>, Mariusz Sochacki <sup>3</sup>, Bartłomiej Stonio<sup>3</sup>, Maciej Galazka <sup>2</sup>, Marcin Pelka <sup>2</sup>, Dominika Kuten <sup>2</sup> and Piotr Niedzielski <sup>1</sup>

**Table S1.** State of the substrates surface before transfer and the quality of graphene on final substratum.

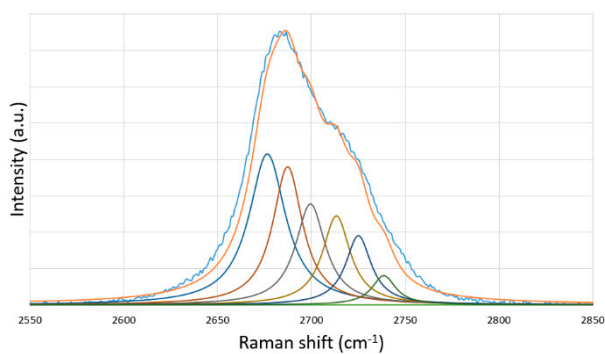
Substratum	Substratum + Graphene
<b>Quartz Glass</b>	
	
<b>PTFE</b>	
	
<b>kapton</b>	
	
<b>PEN</b>	



Raman mapping was performed for graphene transferred on Si/SiO<sub>2</sub> substrate before UV irradiation to check the homogeneity of graphene. Figure S1 exhibits Raman I<sub>2D</sub>/I<sub>G</sub> mapping. Figure S2 shows the fitting of 2D band for trilayer graphene.



**Figure S1.** Raman I<sub>2D</sub>/I<sub>G</sub> imaging of graphene on Si/SiO<sub>2</sub>.



**Figure S2.** Fitting of 2D band for trilayer graphene.



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